

DSPACK 4

Features:

- Isolated mounting base 4000V~
- Pressure contact technology with Increased power cycling capability
- Space and weight saving
- UL Recognized

Typical Applications

- AC/DC Motor drives
- Various rectifiers
- DC supply for PWM inverter

V_{DSM}, V_{RSM}	V_{DRM}, V_{RRM}	Type & Outline
2700V	2600V	DSKT 300/26
2900V	2800V	DSKT 300/28
3100V	3000V	DSKT 300/30
3300V	3200V	DSKT 300/32
3500V	3400V	DSKT 300/34
3700V	3600V	DSKT 300/36

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_J(^{\circ}\text{C})$	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Single side cooled, $T_c=85^{\circ}\text{C}$	125			300	A
$I_{T(RMS)}$	RMS on-state current					471	A
I_{DRM} I_{RRM}	Repetitive peak current	at V_{DRM} at V_{RRM}	125			55	mA
I_{TSM}	Surge on-state current	10ms half sine wave $V_R=60\%V_{RRM}$	125			7.2	kA
I^2t	I^2t for fusing coordination					259	$\text{A}^2\text{s} \times 10^3$
V_{TO}	Threshold voltage		125			0.93	V
r_T	On-state slope resistance					1.00	$\text{m}\Omega$
V_{TM}	Peak on-state voltage	$I_{TM}=900\text{A}$	25			2.45	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=67\%V_{DRM}$	125			800	$\text{V}/\mu\text{s}$
di/dt	Critical rate of rise of on-state current	Gate source 1.5A $t_r \leq 0.5\mu\text{s}$ Repetitive	125			100	$\text{A}/\mu\text{s}$
I_{GT}	Gate trigger current	$V_A=12\text{V}$, $I_A=1\text{A}$	25	30		180	mA
V_{GT}	Gate trigger voltage			0.8		2.5	V
I_H	Holding current			10		200	mA
V_{GD}	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$	125	0.2			V
$R_{th(j-c)}$	Thermal resistance Junction to case	Single side cooled per chip				0.08	$^{\circ}\text{C}/\text{W}$
$R_{th(c-h)}$	Thermal resistance case to heat sink	Single side cooled per chip				0.04	$^{\circ}\text{C}/\text{W}$
V_{iso}	Isolation voltage	50Hz,R.M.S., $t=1\text{min}$, $I_{iso}=1\text{mA}(\text{MAX})$		4000			V
F_m	Terminal connection torque (M10)				12.0		$\text{N}\cdot\text{m}$
	Mounting torque (M6)				6.0		$\text{N}\cdot\text{m}$
T_{vj}	Junction temperature			-40		125	$^{\circ}\text{C}$
T_{stg}	Stored temperature			-40		125	$^{\circ}\text{C}$
W_t	Weight				1275		g

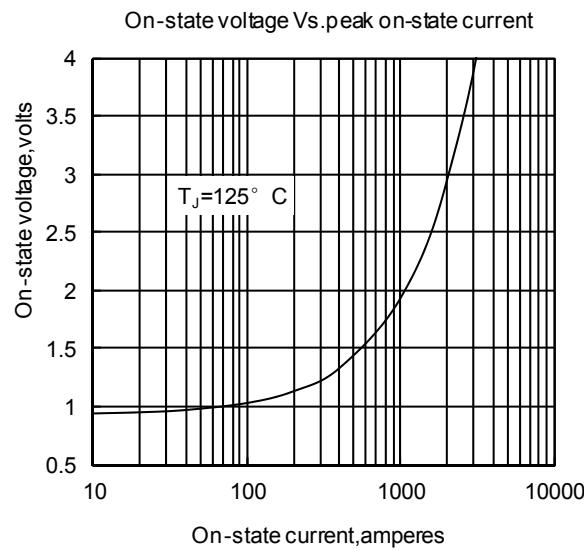


Fig. 1

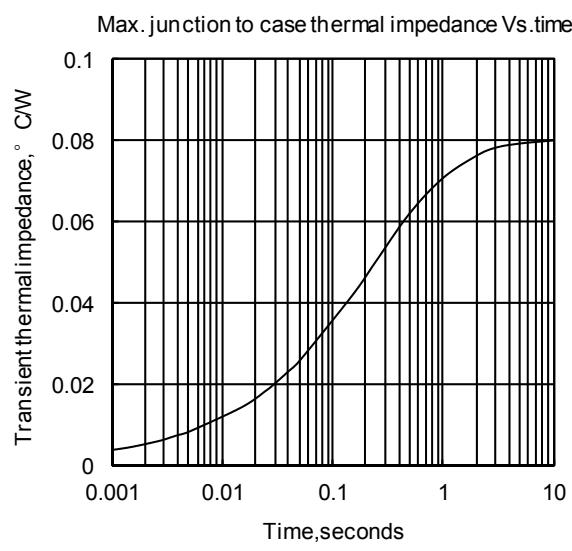


Fig. 2

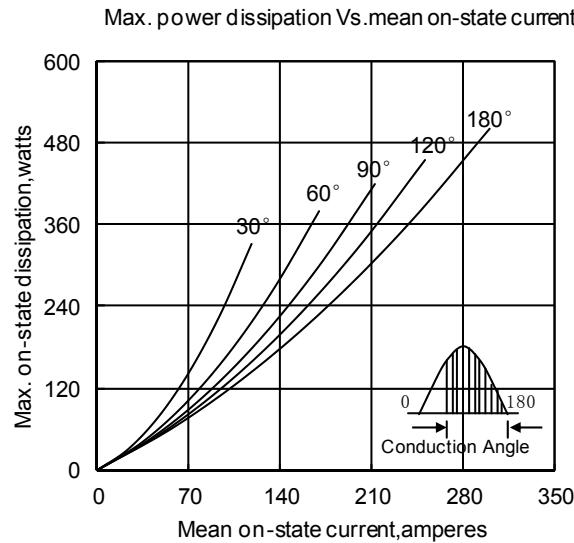


Fig. 3

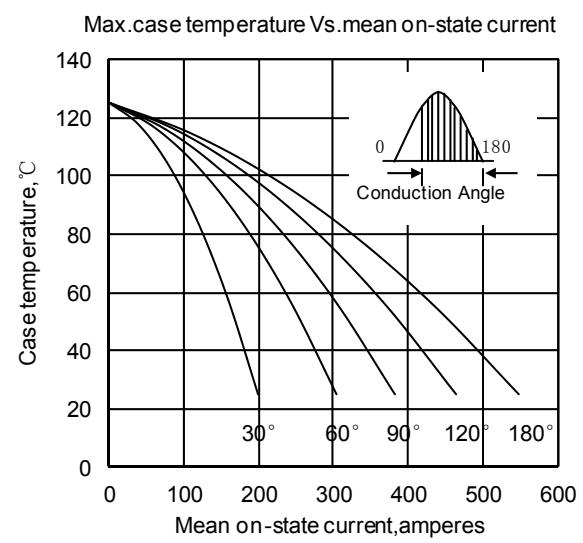


Fig. 4

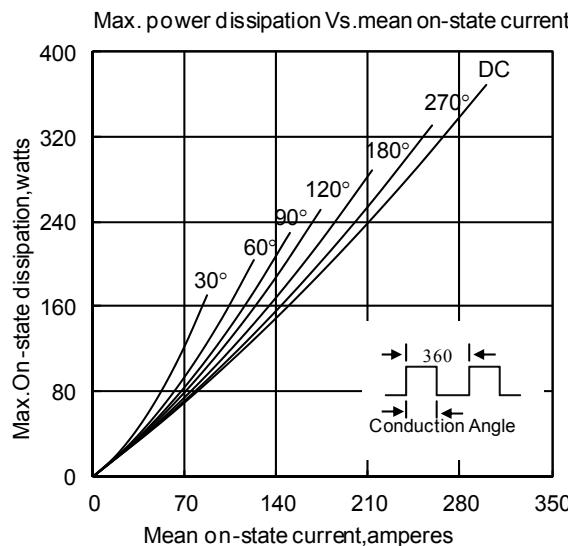


Fig. 5

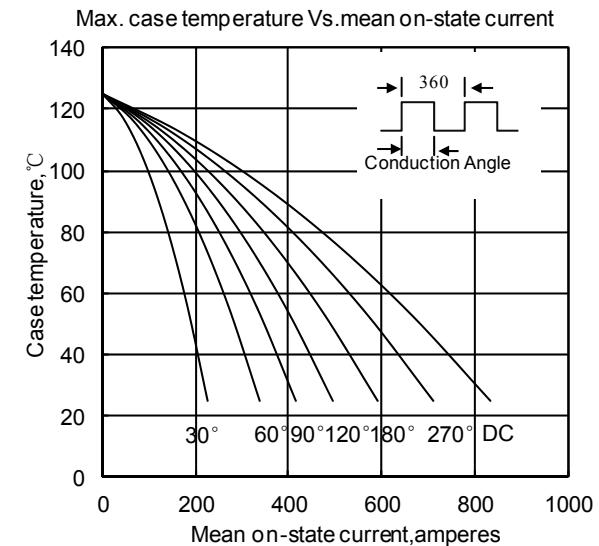


Fig. 6

DYNSEM

DSKT300

Thyristor modules

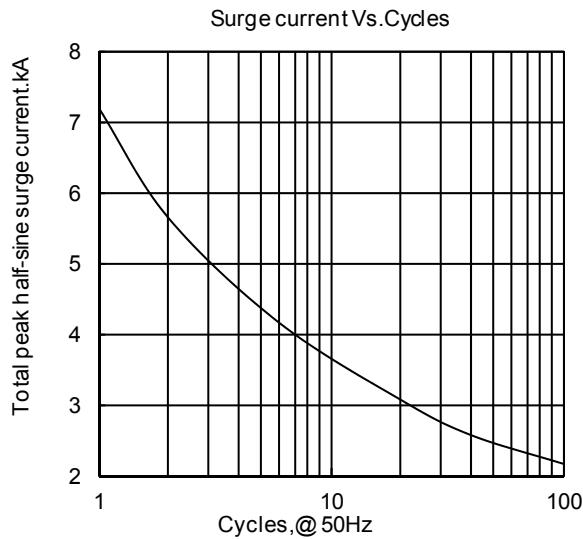


Fig. 7

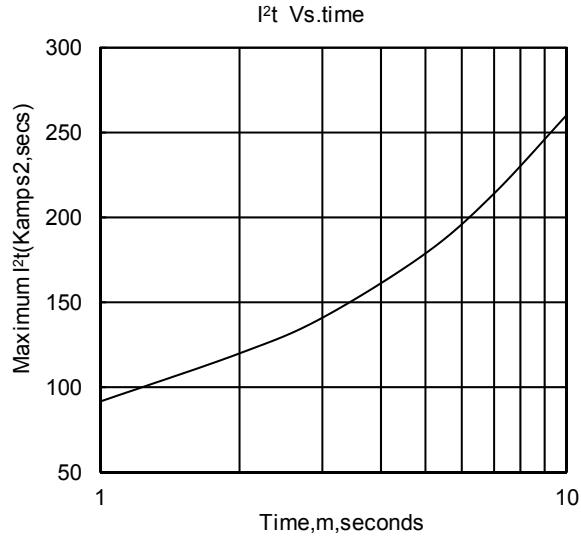


Fig. 8

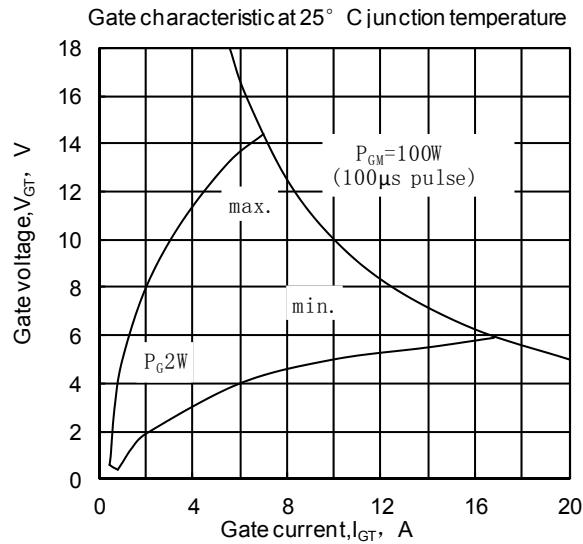


Fig. 9

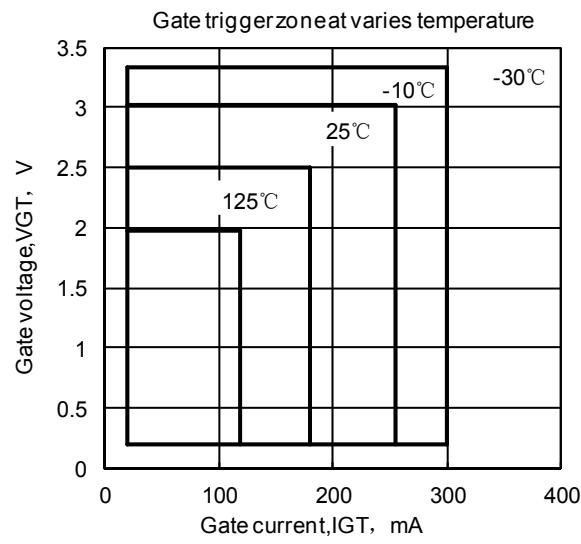


Fig. 10

Outline:

